



T A R G E T
TOP AMPLIFIER RESEARCH GROUPS
IN A EUROPEAN TEAM

RF Device Modelling

- 1 Introduction to RF Device Modelling
- 2 Physical Device Modelling, Part I
- 3 Physical Device Modelling, Part II
- 4 Parasitic Elements Characterisation and De-Embedding
- 5 Electrical Equivalent Circuit Modelling
- 6 Distributed Equivalent Circuit Models
- 7 IMD Properties
- 8 Empirical Device Models: Basics
- 9 Empirical Device Models: Extensions
- 10 Modelling of GaN Devices
- 11 Modelling of MOSFETs
- 12 Modelling of LDMOS Devices
- 13 Modelling of HBTs: Introduction, Modelling Principles and Noise
- 14 Modelling of HBTs: Large-Signal Models, Measurement and Parameter Extraction
- 15 Behavioural Modelling Techniques
- 16 Large-Signal Measurements Based Modelling

Device-Level Linearization Techniques

- 1 Fundamentals of Device Small and Large signal IMD behaviour
- 2 Small and Large Signal Sweet Spots and PA operating class
- 3 Techniques for Understanding Large-Signal IMD behaviour
- 4 IMD Evolution: Load Line and Bias
- 5 Operating Condition Optimization for Improved Linearity
- 6 Nonlinear Measurement Techniques for Accurate Device IMD control
- 7 Specific Device-Based Linearization Techniques: Part I
- 8 Specific Device-Based Linearization Techniques: Part II
- 9 On the CAD "Measurement" of the Device's High Order Derivatives and Dynamics

Modelling for TX System Level Analysis

- 1 System Level Simulation Techniques - Introduction
- 2 Behavioural Modelling Technique: Power and Driver Amplifiers Modelling
- 3 Behavioural Modelling Technique: Mixer Modelling
- 4 Behavioural Modelling Technique: Voltage Controlled Oscillator Modelling
- 5 System Level Analysis by using Behavioural Modelling Techniques

RF Semiconductor Materials and Devices

- 1 Semiconductor Materials I – Structure and Physical Properties
- 2 Semiconductor Materials II – Alloys and Heterostructures
- 3 RF devices I – Figures of Merit and Basic Transistor Concepts
- 4 RF devices II - Transistor Concepts for high Frequency and High Power Applications
- 5 Si- and SiGe-based RF Transistors
- 6 GaAs and InP based RF Transistors
- 7 GaN based RF Transistors
- 8 SiC based Microwave Diodes

TARGET is a Network of Excellence of 49 academic and industrial partners that are active **Europe-wide** in the important fields of microwave power amplifier research and production. Based on its accumulated theoretical and practical expertise TARGET offers **educational services** in the listed fields.

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Microwave Power Amplifier Design

- 1 Power Amplifier Fundamentals
- 2 Non-Linear Characterisation and Modelling Techniques
- 3 Non-Linear Analysis Methods
- 4 Power Amplifier Design Techniques Overview
- 5 High Efficiency Power Amplifiers Design
- 6 Combining Techniques
- 7 Thermal and Packaging Issues
- 8 Linearisation Issues in a Power Amplifier
- 9 Foundry Realisation and Design Rules
- 10 Power Amplifier Design Examples

MW PA Linearisation Techniques

- 1 Overview of Microwave Power Amplifier Linearisation Techniques
- 2 Circuit Level Microwave Power Amplifier Linearisation
- 3 Microwave Power Amplifier Feedback Linearisation
- 4 Microwave Power Amplifier Feedforward Linearisation
- 5 Microwave Power Amplifier Predisortion Linearisation
- 6 Other System Level Microwave Power Amplifier Linearisation Techniques
- 7 Implementation Issues of Microwave Power Amplifier Linearisation Techniques
- 8 Microwave Power Amplifier Linearisation Evaluation Criteria
- 9 PA Linearisation in some Existing and Upcoming Wireless Communication Systems

RF Device Characterisation

- 1 Introduction to RF Device Semiconductor Devices
- 2 Calibration Issues, Static DC and S-Parameter Characterisation
- 3 Pulsed DC and S-Parameter Characterisation
- 4 Extrinsic Characterisation and De-Embedding
- 5 Nonlinear Vector Network Analysis
- 6 Source and Load Pulling Techniques
- 7 Power Amplifier Measurements
- 8 Noise Characterisation
- 9 Thermal Characterisation